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ON THE COVER

Paper-based technology. Paper is the newest material that is beginning to transform the device landscape. This issue of *MRS Bulletin* highlights the use of paper to create novel devices for diagnostics, microfluidics, and electronics that combine low cost and high performance, and how this age-old material is still in its infancy in

this context with intriguing applications. The devices shown on the cover are printed electronic circuits layered onto wax-printed fluidic channels. Image courtesy of Jabulani R. Barber. See the technical theme that begins on page 299.

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